8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Rev. 6 — 12 December 2011

Product data sheet

1. General description

The 74HC595; 74HCT595 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7A.

The 74HC595; 74HCT595 are 8-stage serial shift registers with a storage register and 3-state outputs. The registers have separate clocks.

Data is shifted on the positive-going transitions of the shift register clock input (SHCP). The data in each register is transferred to the storage register on a positive-going transition of the storage register clock input (STCP). If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register.

The shift register has a serial input (DS) and a serial standard output (Q7S) for cascading. It is also provided with asynchronous reset (active LOW) for all 8 shift register stages. The storage register has 8 parallel 3-state bus driver outputs. Data in the storage register appears at the output whenever the output enable input (\overline{OE}) is LOW.

2. Features and benefits

- 8-bit serial input
- 8-bit serial or parallel output
- Storage register with 3-state outputs
- Shift register with direct clear
- 100 MHz (typical) shift out frequency
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Applications

- Serial-to-parallel data conversion
- Remote control holding register



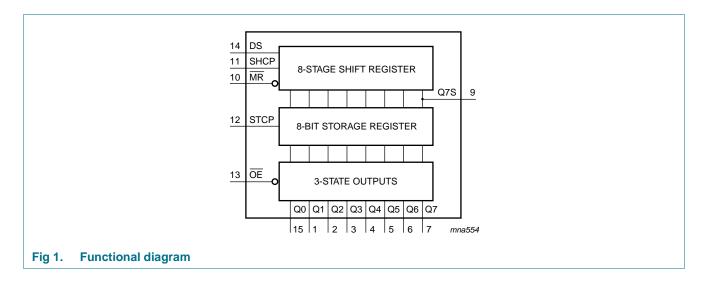
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4. Ordering information

Table 1.Ordering information

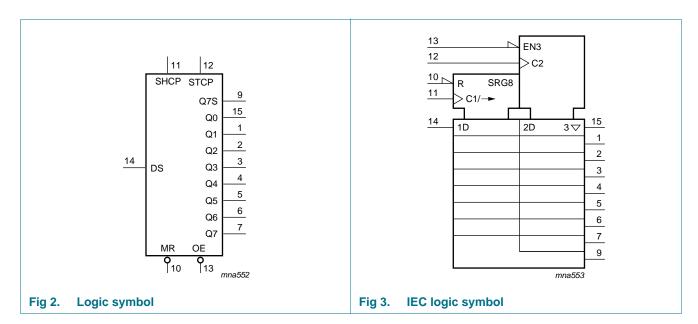
Type number	Package			
	Temperature range	Name	Description	Version
74HC595N -40 °C to +125 °C		DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HCT595N				
74HC595D	5D -40 °C to +125 °C S		plastic small outline package; 16 leads;	SOT109-1
74HCT595D			body width 3.9 mm	
74HC595DB	-40 °C to +125 °C SSOP16		plastic shrink small outline package; 16 leads;	SOT338-1
74HCT595DB			body width 5.3 mm	
74HC595PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT595PW			body width 4.4 mm	
74HC595BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1
74HCT595BQ			very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	

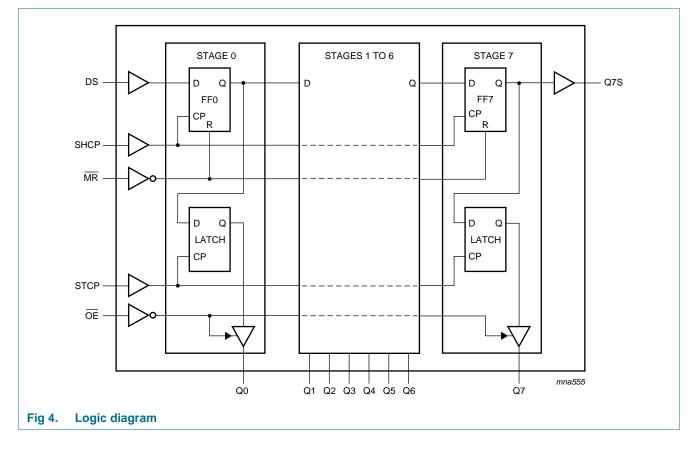
5. Functional diagram



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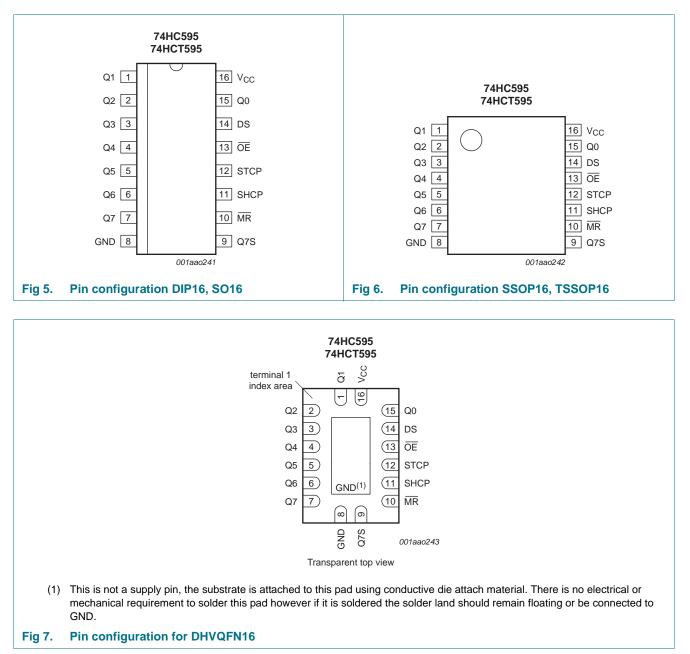
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6. Pinning information

6.1 Pinning



8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

6.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
Q1	1	parallel data output 1
Q2	2	parallel data output 2
Q3	3	parallel data output 3
Q4	4	parallel data output 4
Q5	5	parallel data output 5
Q6	6	parallel data output 6
Q7	7	parallel data output 7
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
OE	13	output enable input (active LOW)
DS	14	serial data input
Q0	15	parallel data output 0
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table^[1]

Contro	bl			Input	Outpu	ıt	Function				
SHCP	STCP	OE	MR	DS	Q7S	Qn					
Х	Х	L	L	Х	L	NC	a LOW-level on $\overline{\text{MR}}$ only affects the shift registers				
Х	\uparrow	L	L	Х	L	L	empty shift register loaded into storage register				
Х	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state				
1	Х	L	Η	Η	Q6S	NC	logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).				
Х	↑	L	Η	Х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages				
1	↑	L	Η	Х	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages				

[1] H = HIGH voltage state;

L = LOW voltage state;

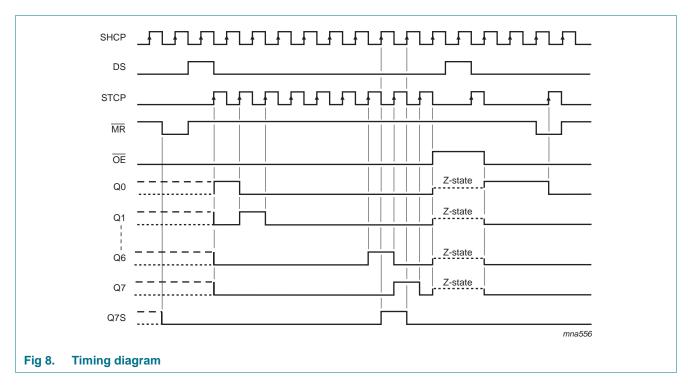
 \uparrow = LOW-to-HIGH transition;

X = don't care;

NC = no change;

Z = high-impedance OFF-state.

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8. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _O	output current	V_{O} = -0.5 V to (V _{CC} + 0.5 V)			
		pin Q7S	-	±25	mA
		pins Qn	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation				
	DIP16 package		<u>[1]</u> -	750	mW
	SO16 package		[2] _	500	mW
	SSOP16 package		[3] _	500	mW
	TSSOP16 package		[3] _	500	mW
	DHVQFN16 package		<u>[4]</u> _	500	mW

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

[4] For DHVQFN16 package: Ptot derates linearly with 4.5 mW/K above 60 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	r Conditions 74HC595				7	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Тур	Max	Min	Max	
74HC595								
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$						
		all outputs						
		I_{O} = –20 $\mu A;$ V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_{O} = –20 $\mu A;$ V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	V
		Q7S output						
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	4.32	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	5.81	-	5.2	-	V
		Qn bus driver outputs						
		$I_{O} = -6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	4.32	-	3.7	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	5.81	-	5.2	-	V

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Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	o +125 ℃	Uni
			Min	Тур	Max	Min	Max	_
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL}						
	output voltage	all outputs						
		$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	V
		Q7S output						
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.33	-	0.4	V
		Qn bus driver outputs						
		$I_0 = 6 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	-	±1.0	μA
oz	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or } \text{GND}$	-	-	±5.0	-	±10	μA
СС	supply current		-	-	80	-	160	μA
G	input capacitance		-	3.5	-	-	-	pF
74HCT59	5							
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
/ _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
/ _{ОН}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$						
	output voltage	all outputs						
		I _O = -20 μA	4.4	4.5	-	4.4	-	V
		Q7S output						
		$I_O = -4 \text{ mA}$	3.84	4.32	-	3.7	-	V
		Qn bus driver outputs						
		$I_O = -6 \text{ mA}$	3.7	4.32	-	3.7	-	V
√ _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$						
	output voltage	all outputs						
		I _O = 20 μA	-	0	0.1	-	0.1	V
		Q7S output						
		I _O = 4.0 mA	-	0.15	0.33	-	0.4	V
		Qn bus driver outputs						
		I _O = 6.0 mA	-	0.16	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±1.0	-	±1.0	μA

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C te	o +125 °C	Unit
			Min	Тур	Max	Min	Max	
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 5.5 \text{ V}; \\ V_{O} = V_{CC} \text{ or } \text{GND}$	-	-	±5.0	-	±10	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	-	160	μA
ΔI_{CC}	additional supply current	per input pin; $I_0 = 0 A$; $V_1 = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V						
		pins \overline{MR} , SHCP, STCP, \overline{OE}	-	150	675	-	735	μA
		pin DS	-	25	113	-	123	μΑ
CI	input capacitance		-	3.5	-	-	-	pF

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

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11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 14</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	−40 °C	to +125 °C	Uni
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74HC59	5										
t _{pd}		SHCP to Q7S; see Figure 9	[2]								
	delay	$V_{CC} = 2 V$		-	52	160	-	200	-	240	ns
		$V_{CC} = 4.5 V$		-	19	32	-	40	-	48	ns
		$V_{CC} = 6 V$		-	15	27	-	34	-	41	ns
		STCP to Qn; see Figure 10	[2]								
		$V_{CC} = 2 V$		-	55	175	-	220	-	265	ns
		$V_{CC} = 4.5 V$		-	20	35	-	44	-	53	ns
		$V_{CC} = 6 V$		-	16	30	-	37	-	45	ns
		MR to Q7S; see Figure 12	[3]								
		$V_{CC} = 2 V$		-	47	175	-	220	-	265	ns
		$V_{CC} = 4.5 V$		-	17	35	-	44	-	53	ns
		$V_{CC} = 6 V$		-	14	30	-	37	-	45	ns
t _{en} enable	enable time	OE to Qn; see Figure 13	<u>[4]</u>								
		$V_{CC} = 2 V$		-	47	150	-	190	-	225	ns
		$V_{CC} = 4.5 V$		-	17	30	-	38	-	45	ns
		$V_{CC} = 6 V$		-	14	26	-	33	-	38	ns
dis	disable time	OE to Qn; see Figure 13	[5]								
		$V_{CC} = 2 V$		-	41	150	-	190	-	225	ns
		$V_{CC} = 4.5 V$		-	15	30	-	38	-	45	ns
		$V_{CC} = 6 V$		-	12	27	-	33	-	38	ns
W	pulse width	SHCP HIGH or LOW; see Figure 9									
		$V_{CC} = 2 V$		75	17	-	95	-	110	-	ns
		$V_{CC} = 4.5 V$		15	6	-	19	-	22	-	ns
		$V_{CC} = 6 V$		13	5	-	16	-	19	-	ns
		STCP HIGH or LOW; see Figure 10									
		$V_{CC} = 2 V$		75	11	-	95	-	110	-	ns
		$V_{CC} = 4.5 V$		15	4	-	19	-	22	-	ns
		$V_{CC} = 6 V$		13	3	-	16	-	19	-	ns
		MR LOW; see Figure 12									
		V _{CC} = 2 V		75	17	-	95	-	110	-	ns
		V _{CC} = 4.5 V		15	6	-	19	-	22	-	ns
		V _{CC} = 6 V		13	5	-	16	-	19	-	ns

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Symbol	Parameter	Conditions			25 °C		-40 °C 1	to +85 °C	–40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
su	set-up time	DS to SHCP; see Figure 10									
		V _{CC} = 2 V		50	11	-	65	-	75	-	ns
		V _{CC} = 4.5 V		10	4	-	13	-	15	-	ns
		V _{CC} = 6 V		9	3	-	11	-	13	-	ns
		SHCP to STCP; see Figure 11									
		$V_{CC} = 2 V$		75	22	-	95	-	110	-	ns
		V _{CC} = 4.5 V		15	8	-	19	-	22	-	ns
		$V_{CC} = 6 V$		13	7	-	16	-	19	-	ns
h	hold time	DS to SHCP; see Figure 11									
		$V_{CC} = 2 V$		3	-6	-	3	-	3	-	ns
		V _{CC} = 4.5 V		3	-2	-	3	-	3	-	ns
		$V_{CC} = 6 V$		3	-2	-	3	-	3	-	ns
rec	recovery	MR to SHCP; see Figure 12									
time	-	V _{CC} = 2 V		50	-19	-	65	-	75	-	ns
		V _{CC} = 4.5 V		10	-7	-	13	-	15	-	ns
		$V_{CC} = 6 V$		9	-6	-	11	-	13	-	ns
max	maximum frequency	SHCP or STCP; see <u>Figure 9</u> and <u>10</u>									
		$V_{CC} = 2 V$		9	30	-	4.8	-	4	-	MH
		V _{CC} = 4.5 V		30	91	-	24	-	20	-	MH
		V _{CC} = 6 V		35	108	-	28	-	24	-	MH
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{\text{CC}}$	<u>[6][7]</u>	-	115	-	-	-	-	-	pF
4HCT59	95; V _{CC} = 4.5	V to 5.5 V									
pd	propagation	SHCP to Q7S; see Figure 9	[2]	-	25	42	-	53	-	63	ns
	delay	STCP to Qn; see Figure 10	[2]	-	24	40	-	50	-	60	ns
		MR to Q7S; see Figure 12	[3]	-	23	40	-	50	-	60	ns
en	enable time	OE to Qn; see Figure 13	[4]	-	21	35	-	44	-	53	ns
dis	disable time	OE to Qn; see Figure 13	[5]	-	18	30	-	38	-	45	ns
W	pulse width	SHCP HIGH or LOW; see Figure 9		16	6	-	20	-	24	-	ns
		STCP HIGH or LOW; see Figure 10		16	5	-	20	-	24	-	ns
		MR LOW; see Figure 12		20	8	-	25	-	30	-	ns
su	set-up time	DS to SHCP; see Figure 10		16	5	-	20	-	24	-	ns
		SHCP to STCP; see Figure 11		16	8	-	20	-	24	-	ns
h	hold time	DS to SHCP; see Figure 11		3	-2	-	3	-	3	-	ns

Table 7. Dynamic characteristics ... continued

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Table 7.	Dynamic	characteristics	continued
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Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 14</u>.

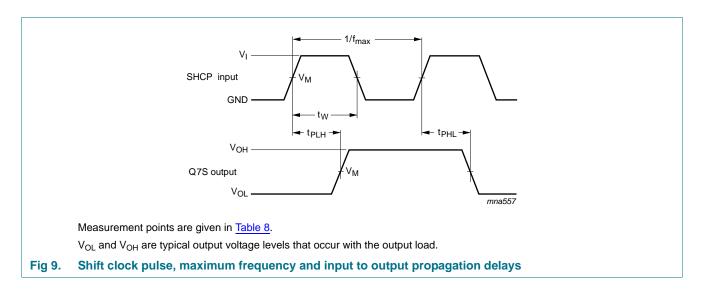
Symbol	Parameter	Conditions		25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Мах	
t _{rec}	recovery time	MR to SHCP; see Figure 12	10	-7	-	13	-	15	-	ns
f _{max}	maximum frequency	SHCP and STCP; see <u>Figure 9</u> and <u>10</u>	30	52	-	24	-	20	-	MHz
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$		130	-	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage.
- [2] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [3] t_{pd} is the same as t_{PHL} only.
- [4] t_{en} is the same as t_{PZL} and t_{PZH} .
- [6] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).
 - $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
 - f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

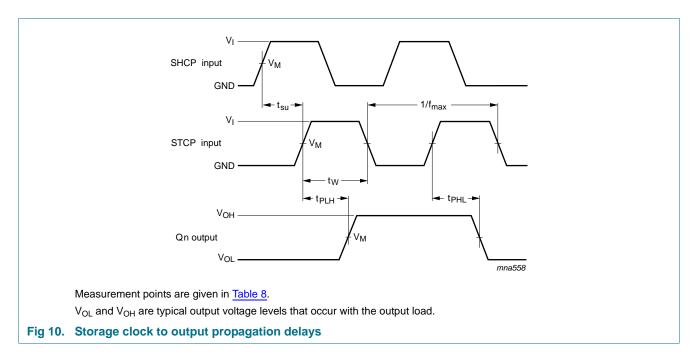
- $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs;
- C_L = output load capacitance in pF;
- V_{CC} = supply voltage in V.
- [7] All 9 outputs switching.

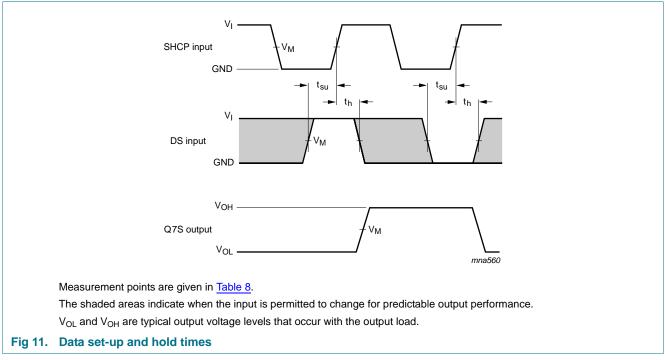
12. Waveforms



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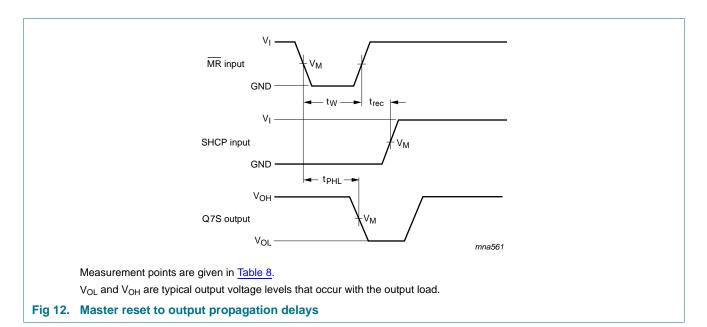


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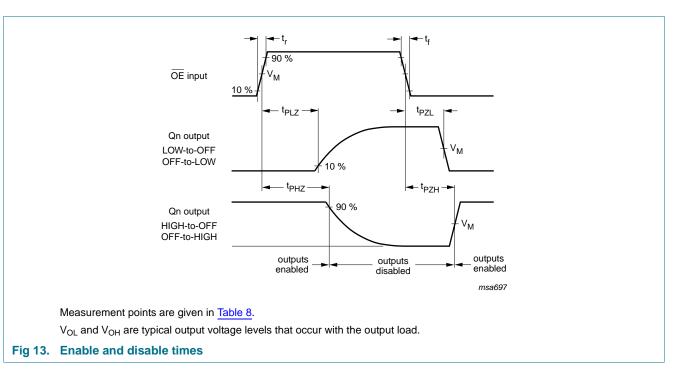


Table 8. Measurement points

Туре	Input	Output	
	V _M	V _M	
74HC595	0.5V _{CC}	0.5V _{CC}	
74HCT595	1.3 V	1.3 V	

74HC_HCT595 Product data sheet

74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

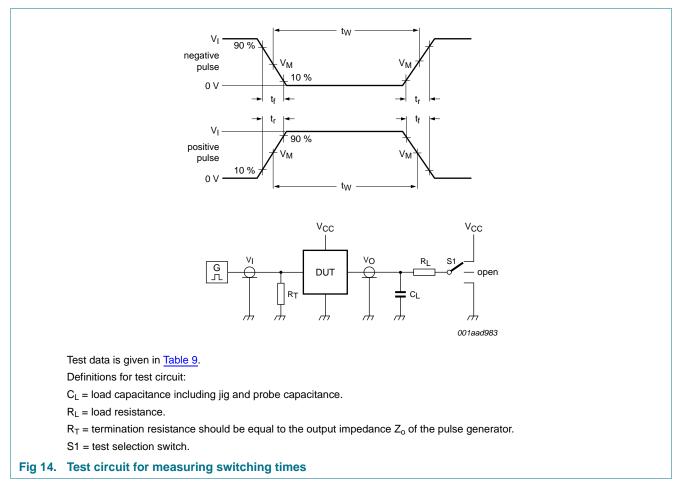


Table 9. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC595	V _{CC}	6 ns	50 pF	1 kΩ	open	GND	V _{CC}
74HCT595	3 V	6 ns	50 pF	1 kΩ	open	GND	V _{CC}

74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

13. Package outline

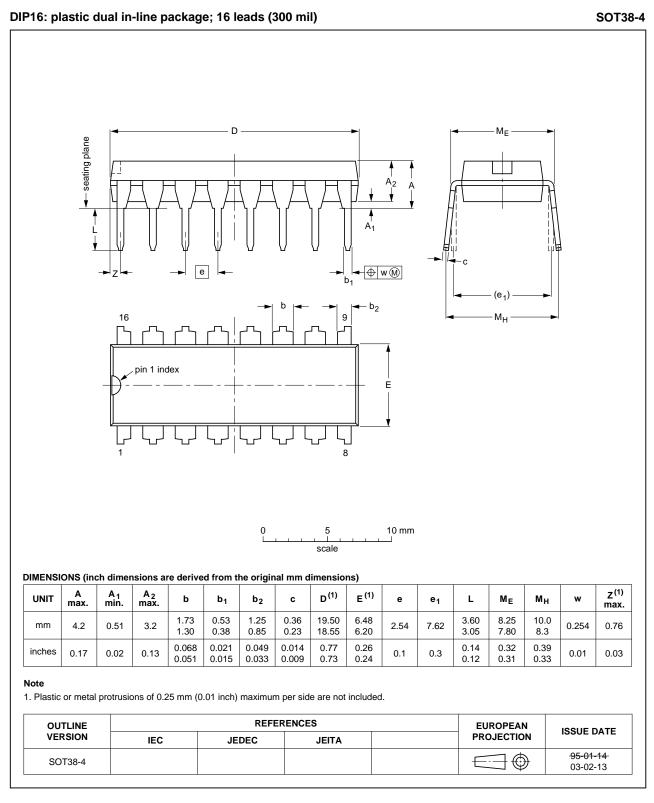


Fig 15. Package outline SOT38-4 (DIP16)

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

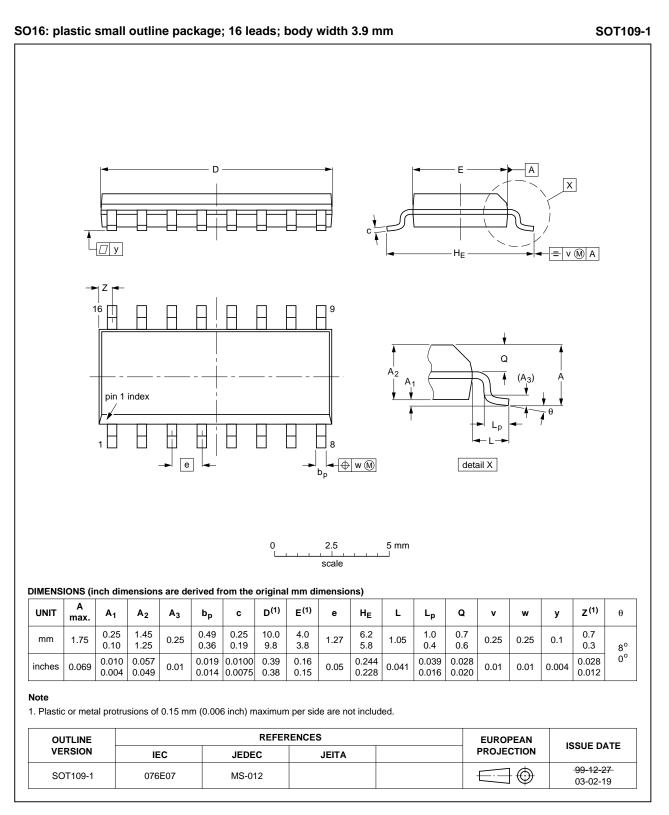


Fig 16. Package outline SOT109-1 (SO16)

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

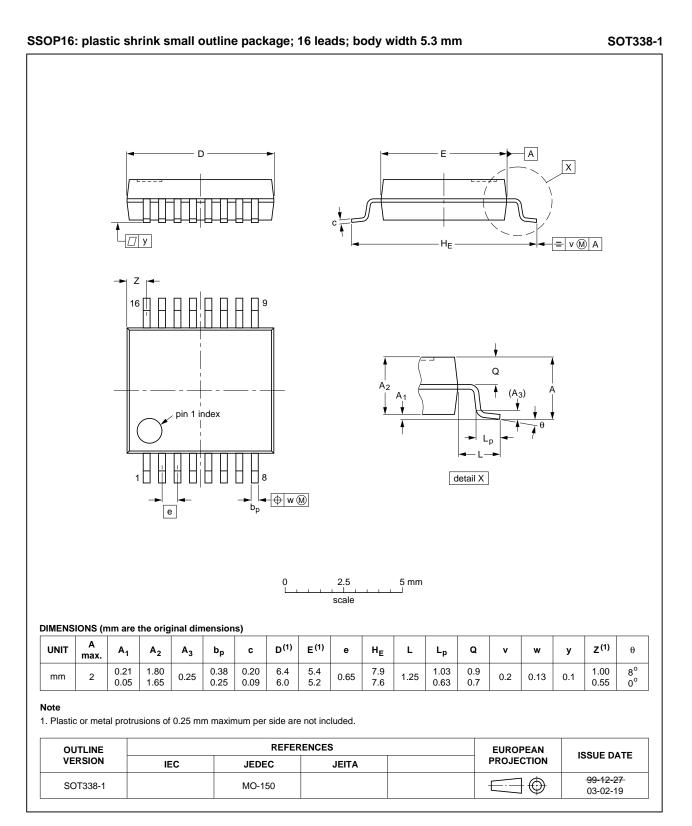


Fig 17. Package outline SOT338-1 (SSOP16)

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

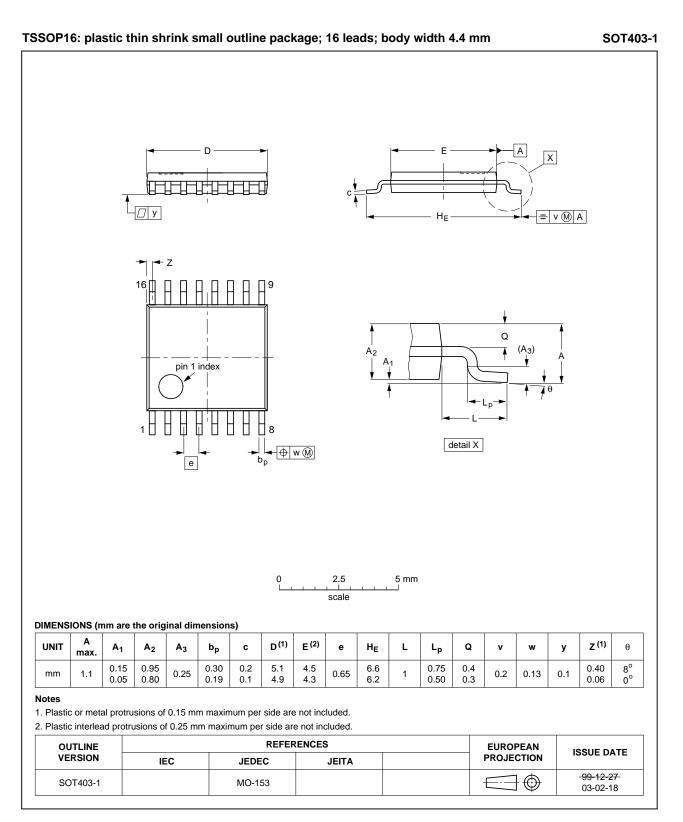
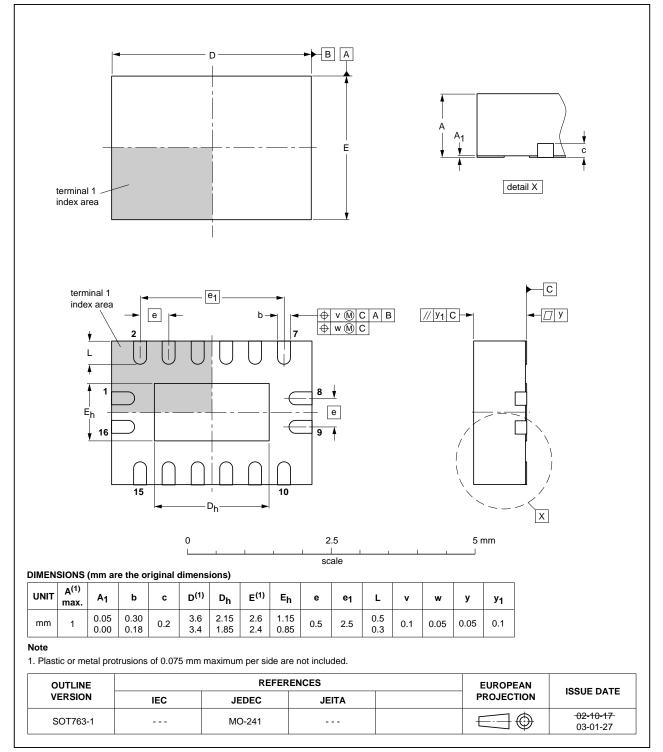


Fig 18. Package outline SOT403-1 (TSSOP16)

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8-bit serial-in, serial or parallel-out shift register with output latches; 3-state



DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 19. Package outline SOT763-1 (DHVQFN16)

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

14. Abbreviations

Table 10. Abbreviations	3
Acronym	Abbreviation
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model

15. Revision history

Table 11. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT595 v.6	20111212	Product data sheet	-	74HC_HCT595 v.5
Modifications:	 Legal pages 	updated.		
74HC_HCT595 v.5	20110628	Product data sheet	-	74HC_HCT595 v.4
74HC_HCT595 v.4	20030604	Product specification	-	74HC_HCT595_CNV v.3
74HC_HCT595_CNV v.3	19980604	Product specification	-	-

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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